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FDS2670 200V N-Channel PowerTrench[®] MOSFET

General Description

This N-Channel MOSFET has been designed specifically to improve the overall efficiency of DC/DC converters using either synchronous or conventional switching PWM controllers.

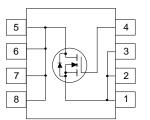
These MOSFETs feature faster switching and lower gate charge than other MOSFETs with comparable $RDS_{(ON)}$ specifications.

The result is a MOSFET that is easy and safer to drive (even at very high frequencies), and DC/DC power supply designs with higher overall efficiency.

Features

- 3.0 A, 200 V. $R_{\text{DS(ON)}}$ = 130 m Ω @ V_{GS} = 10 V
- Low gate charge
- · Fast switching speed
- + High performance trench technology for extremely low $R_{\text{DS}(\text{ON})}$
- High power and current handling capability





Absolute Maximum Ratings TA=25°C unless otherwise noted

Symbol	Parameter		Ratings	Units
V _{DSS}	Drain-Source Voltage		200	V
V _{GSS}	Gate-Source Voltage		±20	V
I _D	Drain Current – Continuous	(Note 1a)	3.0	A
	- Pulsed		20	
P _D	Power Dissipation for Single Operation	(Note 1a)	2.5	W
		(Note 1b)	1.2	
		(Note 1c)	1.0	
dv/dt	Peak Diode Recovery dv/dt	(Note 3)	3.2	V/ns
T _J , T _{STG}	Operating and Storage Junction Temperat	ture Range	-55 to +150	°C

Thermal Characteristics

$R_{\theta JA}$	Thermal Resistance, Junction-to-Ambient	(Note 1a)	50	°C/W
$R_{\theta JA}$	Thermal Resistance, Junction-to-Ambient	(Note 1c)	125	°C/W
$R_{ ext{ hetaJC}}$	Thermal Resistance, Junction-to-Case	(Note 1)	25	°C/W

Package Marking and Ordering Information

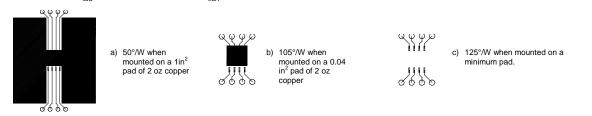
Device Marking	Device	Reel Size	Tape width	Quantity
FDS2670	FDS2670	13"	12mm	2500 units

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Symbol	Parameter	Test Conditions	Min	Тур	Max	Units
Drain-Sc	burce Avalanche Ratings (Note	1)				
W _{DSS}	Single Pulse Drain-Source	$V_{DD} = 100 \text{ V}, I_D = 3.0 \text{ A}$			375	mJ
I _{AR}	Avalanche Energy Maximum Drain-Source Avalanche Current				3.0	A
Off Char	acteristics					
BV _{DSS}	Drain-Source Breakdown Voltage	$V_{GS} = 0 V$, $I_{D} = 250 \mu A$	200			V
ΔBV_{DSS} ΔT_J	Breakdown Voltage Temperature Coefficient	$I_D = 250 \ \mu\text{A}$, Referenced to 25°C		214		mV/°C
DSS	Zero Gate Voltage Drain Current	$V_{DS} = 160 \text{ V}, V_{GS} = 0 \text{ V}$			1	μΑ
GSSF	Gate–Body Leakage, Forward	$V_{GS} = 20 \text{ V}, \qquad V_{DS} = 0 \text{ V}$			100	nA
GSSR	Gate–Body Leakage, Reverse	$V_{GS} = -20 \text{ V} \qquad V_{DS} = 0 \text{ V}$			-100	nA
On Char	acteristics (Note 2)					
V _{GS(th)}	Gate Threshold Voltage	$V_{DS} = V_{GS}$, $I_D = 250 \mu A$	2	4	4.5	V
<u>ΔV_{GS(th)}</u> ΔT _J	Gate Threshold Voltage Temperature Coefficient	$I_D = 250 \ \mu\text{A}$, Referenced to 25°C		-10		mV/°C
R _{DS(on)}	Static Drain–Source On–Resistance			100 205	130 275	mΩ
D(on)	On–State Drain Current	$V_{GS}=10~V, \qquad V_{DS}=10~V$	20			Α
9 _{FS}	Forward Transconductance	$V_{DS} = 10 V$, $I_{D} = 3.0 A$		15		S
Dvnamic	Characteristics					
C _{iss}	Input Capacitance	$V_{DS} = 100 \text{ V}, V_{GS} = 0 \text{ V},$		1228		pF
C _{oss}	Output Capacitance	f = 1.0 MHz		112		pF
Crss	Reverse Transfer Capacitance			17		pF
Switchin	g Characteristics (Note 2)					
d(on)	Turn–On Delay Time	$V_{DD} = 100 V$, $I_D = 1 A$,		13	23	ns
r	Turn–On Rise Time	$V_{GS} = 10 \text{ V}, R_{GEN} = 6 \Omega$		8	16	ns
d(off)	Turn–Off Delay Time	-		30	48	ns
f	Turn–Off Fall Time			25	40	ns
Qg	Total Gate Charge	$V_{DS} = 100 \text{ V}, I_{D} = 3 \text{ A},$		27	43	nC
Q _{gs}	Gate–Source Charge	V _{GS} = 10 V		7		nC
Q _{gd}	Gate–Drain Charge			10		nC
Drain-Se	ource Diode Characteristics	and Maximum Ratings				
s	Maximum Continuous Drain–Source				2.1	Α
V _{SD}	Drain–Source Diode Forward Voltage	$V_{GS} = 0 V$, $I_{S} = 2.1 A$ (Note 2)		0.7	1.2	V

Notes:

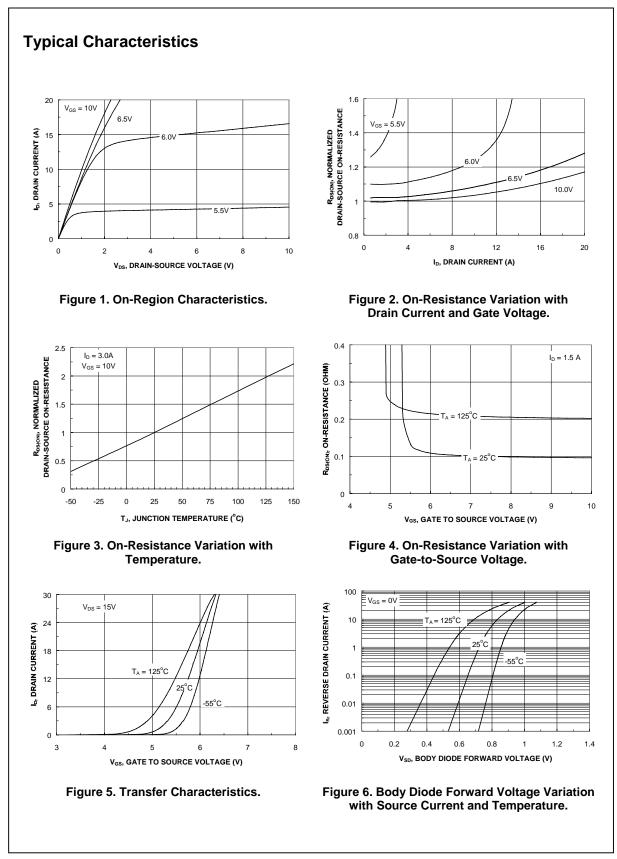
1. R_{6JA} is the sum of the junction-to-case and case-to-ambient thermal resistance where the case thermal reference is defined as the solder mounting surface of the drain pins. R_{6JC} is guaranteed by design while R_{6CA} is determined by the user's board design.

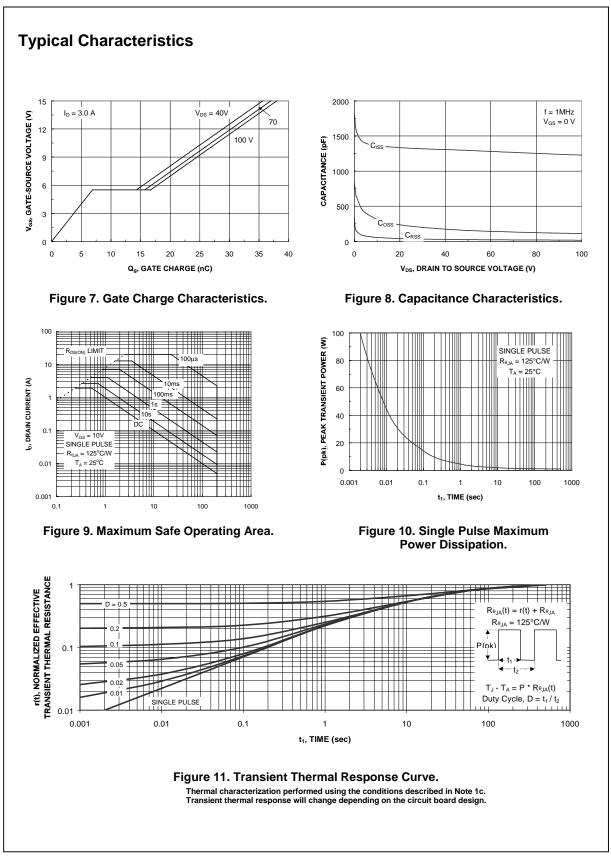


Scale 1 : 1 on letter size paper

2. Pulse Test: Pulse Width < 300µs, Duty Cycle < 2.0%

3. $I_{SD} \leq$ 3A, di/dt \leq 100A/µs, $V_{DD} \leq BV_{DSS},$ Starting T_J = 25°C





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